**Product data sheet** 

### 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 2. Features and benefits

- Low threshold voltage
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

## 3. Applications

- · High-side load switch
- Battery management
- DC-to-DC conversion
- Switching circuits

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V	
V <sub>GS</sub>	gate-source voltage			-12	-	12	V	
I <sub>D</sub>	drain current	$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$	[1]	-	-	-17.2	Α	
Static characte	Static characteristics							
R <sub>DSon</sub>	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -10.5 \text{ A}; T_j = 25 \text{ °C}$		-	9.1	11.4	mΩ	
	resistance	$V_{GS}$ = -2.5 V; $I_D$ = -8 A; $T_j$ = 25 °C		-	14.8	19.7	mΩ	

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source	ر ف-ق-ق-ق	
3	S	source		
4	G	gate	]	
5	D	drain		
6	D	drain	المممكا	Š 017aaa257
7	D	drain	8 7 6 5	
8	D	drain	MLPAK33 (SOT8002-1)	

# 6. Ordering information

**Table 3. Ordering information** 

Type number Package						
	Name	Description	Version			
PXP011-20QX		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1			

## 7. Marking

#### **Table 4. Marking codes**

Type number	Marking code
PXP011-20QX	9AV

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-17.2	А
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-10.5	Α
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	-6.6	А
		V <sub>GS</sub> = -4.5 V; T <sub>sp</sub> = 25 °C		-	-56.6	Α
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-93	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	4.8	W
		T <sub>amb</sub> = 25 °C	[1]	-	1.8	W
		T <sub>sp</sub> = 25 °C		-	50	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode		1	1	1	
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1.7	Α

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

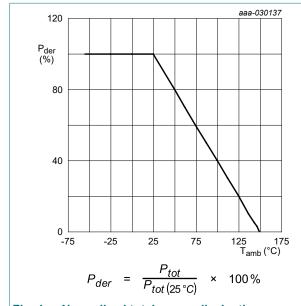


Fig. 1. Normalized total power dissipation as a function of ambient temperature

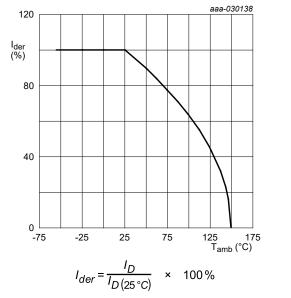


Fig. 2. Normalized continuous drain current as a function of ambient temperature

#### 20 V, P-channel Trench MOSFET

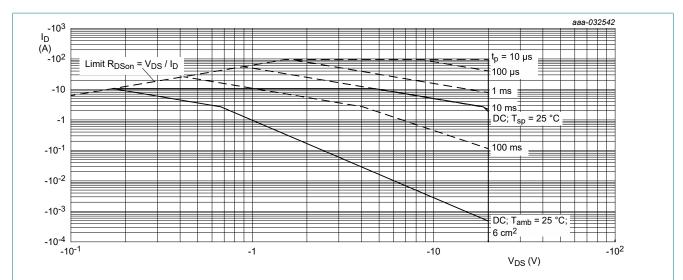


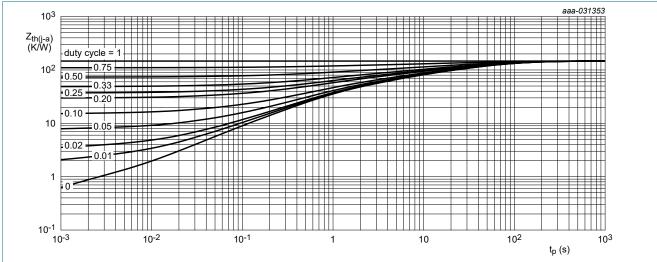
Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	145	185	K/W
	junction to ambient		[2]	-	55	70	K/W
		in free air; t ≤ 5 s	[2]	-	21	26	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	1.5	2.5	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

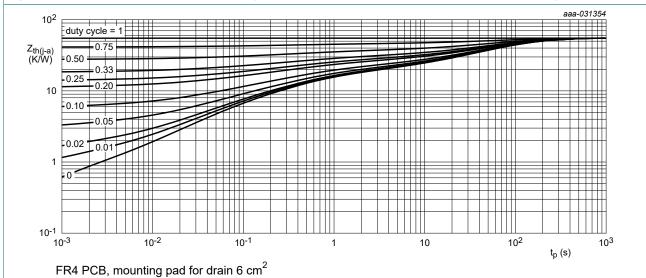


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 10. Characteristics

#### Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = -250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-20	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-0.7	-0.9	-1.25	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = -20 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -12 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-0.1	μA
		V <sub>GS</sub> = 12 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	0.1	μA
R <sub>DSon</sub>	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -10.5 \text{ A}; T_j = 25 \text{ °C}$	-	9.1	11.4	mΩ
	resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -10.5 A; T <sub>j</sub> = 150 °C	-	12.9	16.2	mΩ
		$V_{GS}$ = -2.5 V; $I_D$ = -8 A; $T_j$ = 25 °C	-	14.8	19.7	mΩ
9fs	forward transconductance	$V_{DS}$ = -10 V; $I_D$ = -10.5 A; $T_j$ = 25 °C	-	52	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	2.3	-	Ω
Dynamic ch	aracteristics		1		<u> </u>	
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = -10 V; I <sub>D</sub> = -10.5 A; V <sub>GS</sub> = -4.5 V;	-	43.4	65.1	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	6.9	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge		-	3.7	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	3.2	-	nC
$Q_{GD}$	gate-drain charge		-	14.2	-	nC
$V_{GSpl}$	gate-source plateau voltage	$V_{DS}$ = -10 V; $I_D$ = -10.5 A; $T_j$ = 25 °C	-	-1.7	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -10 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	4200	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	630	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	580	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = -10 \text{ V}; I_D = -8 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	11	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	33	-	ns
t <sub>d(off)</sub>	turn-off delay time	1	-	69	-	ns
t <sub>f</sub>	fall time	1	-	44	-	ns
Source-drai	in diode		1		-	
V <sub>SD</sub>	source-drain voltage	$I_S = -1.7 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-0.7	-1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = -1.7 A; dI <sub>S</sub> /dt = 100 A/μs;	-	28	-	ns
Q <sub>r</sub>	recovered charge	$V_{GS} = -4.5 \text{ V}; V_{DS} = -10 \text{ V}; T_j = 25 \text{ °C}$	-	17	-	nC
t <sub>a</sub>	reverse recovery rise time		-	13	-	ns
t <sub>b</sub>	reverse recovery fall time		-	15	-	ns

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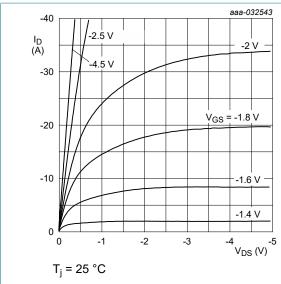
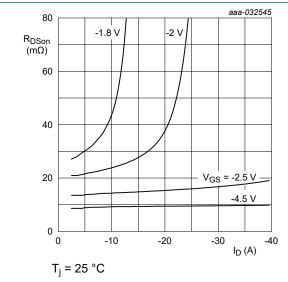
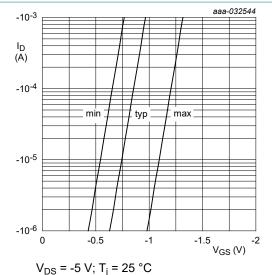


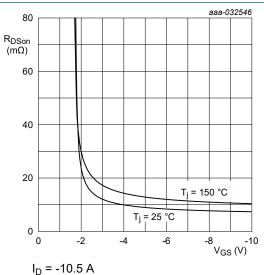
Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values



Drain-source on-state resistance as a function Fig. 8. of drain current; typical values



Sub-threshold drain current as a function of Fig. 7. gate-source voltage



Drain-source on-state resistance as a function Fig. 9. of gate-source voltage; typical values

#### 20 V, P-channel Trench MOSFET

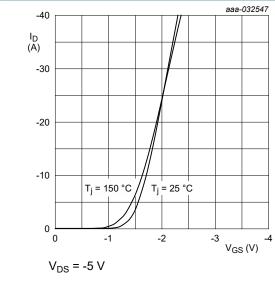


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

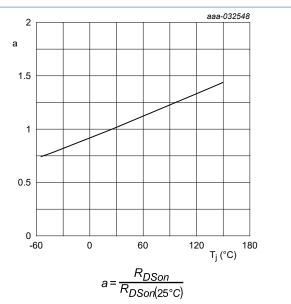


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

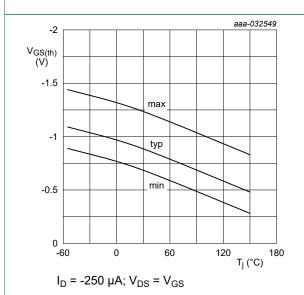


Fig. 12. Gate-source threshold voltage as a function of junction temperature

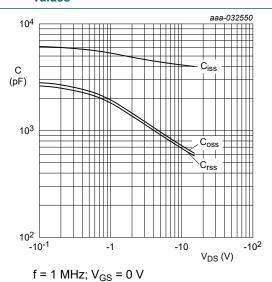


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

### 20 V, P-channel Trench MOSFET

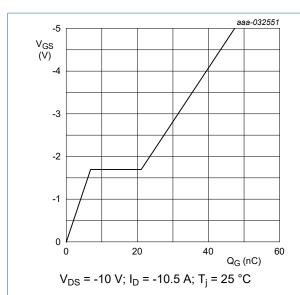


Fig. 14. Gate-source voltage as a function of gate charge; typical values

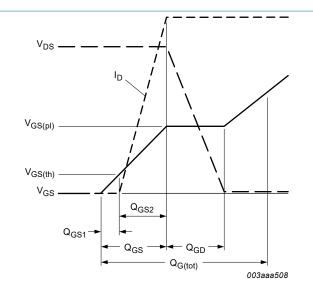


Fig. 15. Gate charge waveform definitions

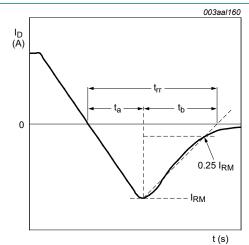


Fig. 16. Reverse recovery timing definition

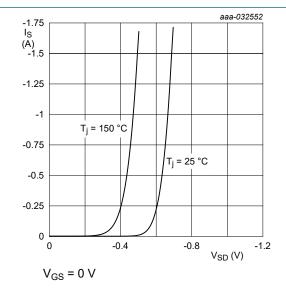
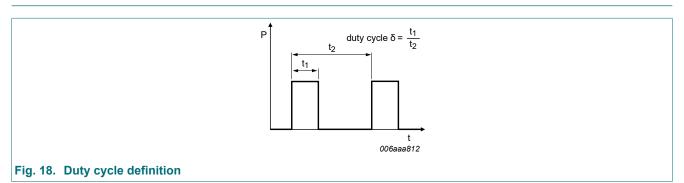


Fig. 17. Source current as a function of source-drain voltage; typical values

### 11. Test information



20 V, P-channel Trench MOSFET

## 12. Package outline

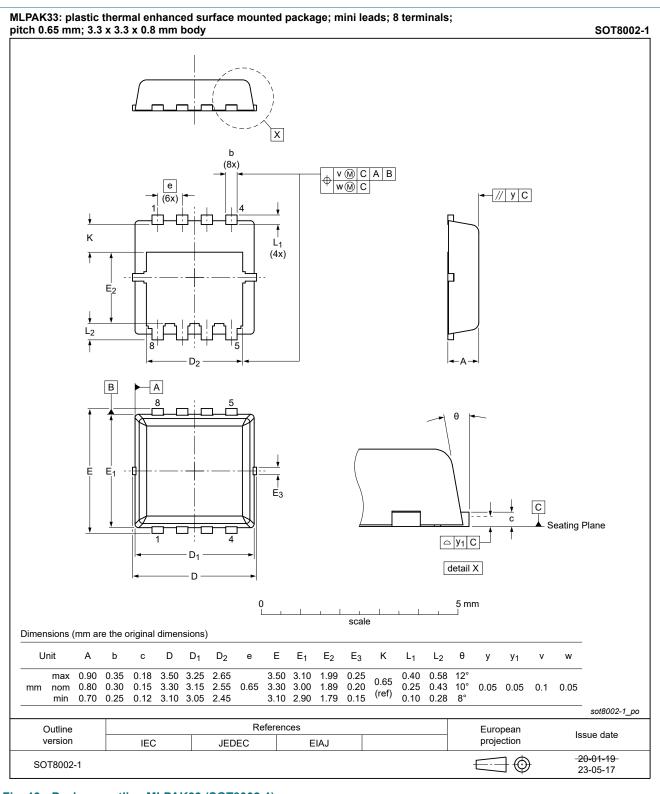
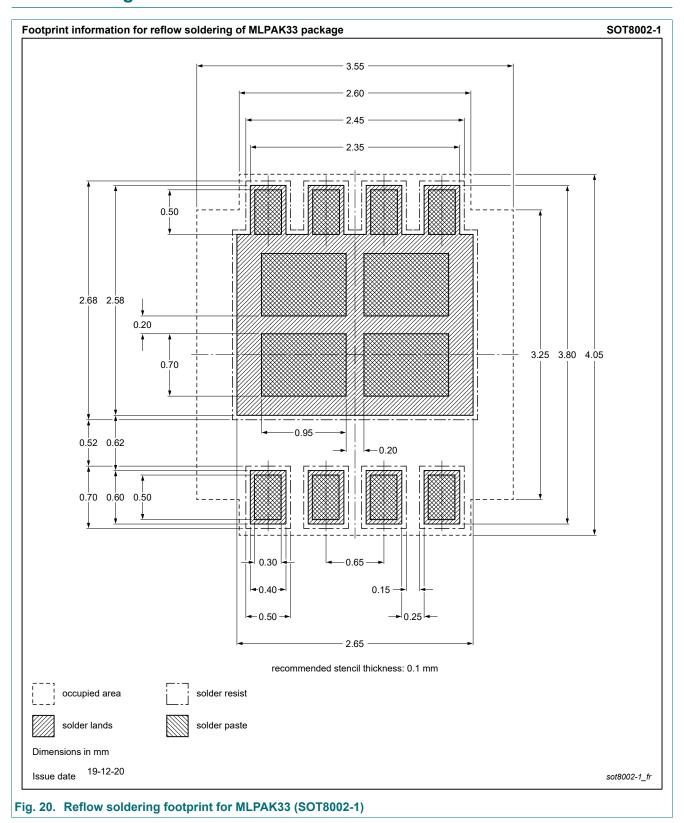


Fig. 19. Package outline MLPAK33 (SOT8002-1)

20 V, P-channel Trench MOSFET

## 13. Soldering



20 V, P-channel Trench MOSFET

# 14. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PXP011-20QX v.2	20230731	Product data sheet	-	PXP011-20QX v.1			
Modifications:	Chapter "Package or	Chapter "Package outline": drawing update					
PXP011-20QX v.1	20210105	Product data sheet	-	-			

#### 20 V, P-channel Trench MOSFET

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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PXP011-20QX

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